2N918

NPN SILICON RF TRANSISTOR



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N918 type is an NPN silicon RF transistor, manufactured by the epitaxial planar process and designed for high frequency amplifier and oscillator applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T_A=25°C unless otherwise noted) SYMBOL **UNITS** Collector-Base Voltage V_{CBO} 30 Collector-Emitter Voltage 15 ٧ VCEO Emitter-Base Voltage V_{EBO} 3.0 ٧ Continuous Collector Current 50 mΑ ΙC Power Dissipation 200 mW P_{D} Power Dissipation (T_C=25°C) 300 $\, mW \,$ P_{D} Operating and Storage Junction Temperature T_J, T_{stg} -65 to +200 °С Thermal Resistance Θ_{JA} 87.5 °C/W Thermal Resistance 58.3 °C/W Θ JC **ELECTRICAL CHARACTERISTICS**: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
ICBO	V _{CB} =15V		10	nA
I _{CBO}	V _{CB} =15V, T _A =150°C		1.0	μΑ
BV _{CBO}	I _C =1.0μA	30		V
BVCEO	I _C =3.0mA	15		V
BV EBO	I _E =10μA	3.0		V
VCE(SAT)	I _C =10mA, I _B =1.0mA		0.4	V
V _{BE(SAT)}	I _C =10mA, I _B =1.0mA		1.0	V
hFE	V_{CE} =1.0V, I_{C} =3.0mA	20		
fT	V_{CE} =10V, I_{C} =4.0mA, f=100MHz	600		MHz
C_{ob}	V_{CB} =10V, I_E =0, f=1.0MHz		1.7	pF
C_{ob}	V _{EB} =0, I _E =0, f=1.0MHz		3.0	pF
C _{ib}	V_{EB} =0.5V, I_{C} =0, f=1.0MHz		2.0	pF
P_0	V_{CB} =15V, I_{C} =8.0mA, f=500MHz	30		mW
G _{pe}	V_{CB} =12V, I_{C} =6.0mA, f=200MHz	15		dB
η	V_{CB} =15V, I_{C} =8.0mA, f=500MHz	25		%
NF	V _{CE} =6.0V, I _C =1.0mA,			
	R_G =400 Ω , f=60kHz		6.0	dB

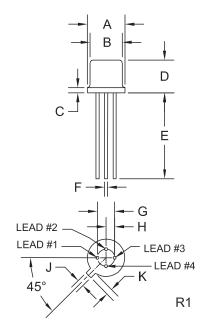
R1 (11-September 2012)

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TO-72 CASE - MECHANICAL OUTLINE



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A (DIA)	0.209	0.230	5.31	5.84			
B (DIA)	0.175	0.195	4.45	4.95			
С	-	0.030		0.76			
D	0.170	0.210	4.32	5.33			
Е	0.500	-	12.70	-			
F (DIA)	0.016	0.019	0.41	0.48			
G (DIA)	0.100		2.54				
Н	0.050		1.27				
J	0.036	0.046	0.91	1.17			
K	0.028	0.048	0.71	1.22			

TO-72 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector 4) Case

MARKING: FULL PART NUMBER

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- · Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- · PbSn plating options
- Package details
- · Application notes
- · Application and design sample kits
- Custom product and package development

CONTACT US

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